# R&S®SGT100A SGMA Vector RF Source Specifications



Data Sheet | 03.00

### **CONTENTS**

Definitions	3
Key features	4
Specifications	5
RF performance	5
Frequency	5
Reference frequency	5
Level	6
Spectral purity	8
Phase coherence (R&S®SGT-K90 option)	9
Simultaneous modulation	9
Pulse modulation (R&S®SGT-K22 option)	10
Input for external pulse modulation	10
Internal pulse generator	10
I/Q modulation	11
I/Q modulator	11
Baseband bypass mode for externally generated I/Q signals	13
Analog I/Q inputs	13
Internal baseband I/Q	13
Analog I/Q outputs (R&S®SGT-K16 option)	14
Envelope tracking (R&S®SGT-K540 option)	15
Envelope ARB (R&S®SGT-K543 option)	15
AM/AM, AM/φM predistortion (R&S®SGT-K541 option)	16
Arbitrary waveform generator (R&S®SGT-K510 option)	17
Multisegment and multicarrier arbitrary waveform mode	18
Modulation performance for GSM/EDGE and 3GPP FDD digital standards	19
Digital standards with R&S®WinIQSIM2™	20
Digital baseband connectivity (R&S®SGT-K18 option)	21
Internal additive white Gaussian noise (AWGN, R&S®SGT-K62 option)	22
Remote control	22
Connectors	23
Rear panel connectors	23
General data	24
Ordering information	25

### **Definitions**

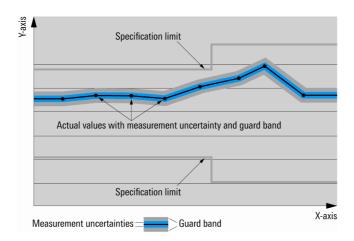
#### General

Product data applies under the following conditions:

- Three hours storage at ambient temperature followed by 30 minutes warm-up operation
- Specified environmental conditions met
- · Recommended calibration interval adhered to
- · All internal automatic adjustments performed, if applicable

#### Specifications with limits

Represent warranted product performance by means of a range of values for the specified parameter. These specifications are marked with limiting symbols such as  $\langle , \leq , > , \geq , \pm \rangle$ , or descriptions such as maximum, limit of, minimum. Compliance is ensured by testing or is derived from the design. Test limits are narrowed by guard bands to take into account measurement uncertainties, drift and aging, if applicable.



#### Specifications without limits

Represent warranted product performance for the specified parameter. These specifications are not specially marked and represent values with no or negligible deviations from the given value (e.g. dimensions or resolution of a setting parameter). Compliance is ensured by design.

### Typical data (typ.)

Characterizes product performance by means of representative information for the given parameter. When marked with <, > or as a range, it represents the performance met by approximately 80 % of the instruments at production time. Otherwise, it represents the mean value.

#### Nominal values (nom.)

Characterize product performance by means of a representative value for the given parameter (e.g. nominal impedance). In contrast to typical data, a statistical evaluation does not take place and the parameter is not tested during production.

#### Measured values (meas.)

Characterize expected product performance by means of measurement results gained from individual samples.

#### **Uncertainties**

Represent limits of measurement uncertainty for a given measurand. Uncertainty is defined with a coverage factor of 2 and has been calculated in line with the rules of the Guide to the Expression of Uncertainty in Measurement (GUM), taking into account environmental conditions, aging, wear and tear.

Device settings and GUI parameters are indicated as follows: "parameter: value".

Typical data as well as nominal and measured values are not warranted by Rohde & Schwarz.

### **Key features**

### **Dedicated ATE digital source**

- I/Q modulated RF source in the frequency range from 1 MHz to 3 GHz or 6 GHz
- · Very fast frequency and level setting times via PCIe interface
- Maximum level of +22 dBm (typ.)
- · Wear-free electronic attenuator
- Integrated ARB with up to 1 Gsample memory depth and 240 MHz RF bandwidth
- External software (R&S®SGMA GUI) for remote control of multiple instruments
- Field-upgradeable

#### Compact, space-saving solution

- Smallest signal generator in its class: 1 HU, ½ × 19"
- Lightweight

#### High performance at an attractive price

- Low SSB phase noise of typ. -133 dBc (measured, 20 kHz carrier offset, f = 1 GHz, 1 Hz measurement bandwidth)
- Wideband noise of < -145 dBc (CW)
- Nonharmonics of < -76 dBc (> 10 kHz carrier offset, f ≤ 1500 MHz, CW)
- · Very high level accuracy and repeatability
- Optional pulse modulation capability and internal pulse generator
- · Optional high-stability reference oscillator
- · Optional coherent LO input/output

#### Minimized total cost of ownership

- · Attractive initial cost
- · Long, three-year calibration interval
- · Simplified error diagnostics through built-in selftests

# **Specifications**

# RF performance

### **Frequency**

Frequency range	CW mode	1 MHz to 3 GHz	
	I/Q mode, internal baseband	1 MHz to 3 GHz	
	I/Q mode, external analog	80 MHz to 3 GHz	
	with R&S®SGT-KB106 option	with R&S®SGT-KB106 option	
	CW mode	1 MHz to 6 GHz	
	I/Q mode, internal baseband	1 MHz to 6 GHz	
	I/Q mode, external analog	80 MHz to 6 GHz	
Resolution of setting		0.001 Hz	
Resolution of synthesis	f = 1 GHz	0.174 μHz (nom.)	
Setting time	to within		
	$< 2 \times 10^{-7}$ for f > 500 MHz or $< 100$ Hz	< 2 × $10^{-7}$ for f > 500 MHz or < 100 Hz for f ≤ 500 MHz	
	with PCIe remote control	< 500 µs	
Resolution of phase offset setting	0.1°		

### Reference frequency

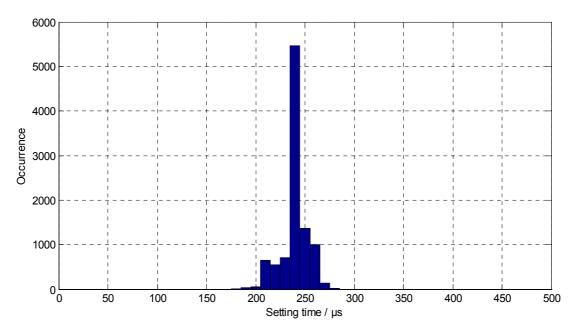
Frequency error	at time of calibration in production	< 1 × 10 <sup>-7</sup>
	with R&S®SGT-B1 option	< 1 × 10 <sup>-8</sup>
Aging		< 1 × 10 <sup>-6</sup> /year
(after 30 days of uninterrupted operation)	with R&S®SGT-B1 option	< 1 × 10 <sup>-9</sup> /day, < 1 × 10 <sup>-7</sup> /year
Temperature effect (0 °C to +50 °C)	·	< 2 × 10 <sup>-6</sup>
	with R&S®SGT-B1 option	< 1 × 10 <sup>-7</sup>
Warm-up time	to nominal thermostat temperature	≤ 10 min
	(with R&S®SGT-B1 option only)	
Reference frequency output		
Connector type	REF/LO OUT on rear panel	SMA female
Output frequency	sine wave	
	instrument set to internal reference	10 MHz, 1000 MHz
	instrument set to external reference	applied external reference input frequency
		or 1000 MHz
Output level		+6 dBm to +12 dBm; 9 dBm (typ.)
Source impedance		50 Ω (nom.)
Reference frequency input		
Connector type	REF/LO IN on rear panel	SMA female
Input frequency		10 MHz, 100 MHz, 1000 MHz
Frequency locking range		±10 × 10 <sup>-6</sup>
Input level range		0 dBm to +16 dBm
Input impedance		50 Ω (nom.)

#### Level

Setting characteristic: auto – The step attenuator is switched over automatically. The output level is specified over the full range from –120 dBm to +17 dBm.

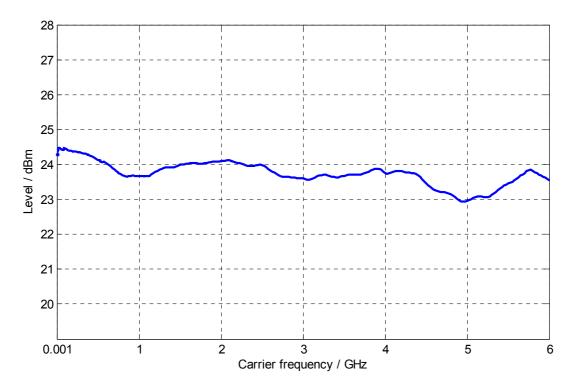
**Setting characteristic: uninterrupted level setting –** The level is set without changing the step attenuator. The step attenuator is fixed to the current setting. Level changes are performed without interruption. The maximum interruption-free setting range is limited. If this range is exceeded, the spectral purity of the output signal decreases.

Setting range		-120 dBm to +25 dBm
Specified level range		-120 dBm to +17 dBm (PEP) 1
Resolution of setting	0.01 dB	
Level error	setting characteristic: auto, temperature range from +18 °C to +33 °C,	
	CW and I/Q (full-scale)	
	1 MHz ≤ f ≤ 3 GHz, level ≤ 15 dBm	< 0.5 dB
	1 MHz ≤ f ≤ 3 GHz,	< 0.7 dB
	15 dBm < level ≤ 17 dBm	
	3 GHz < f ≤ 6 GHz	< 0.9 dB
Additional level error for pulse modulation	pulse width ≥ 100 ns	< 0.3 dB (meas.)
Output impedance VSWR in 50 Ω system	in full frequency range,	< 1.8
	setting characteristic: auto	
Setting time	to < 0.1 dB deviation from final value,	< 500 µs
	setting characteristic: auto, with PCIe	
	remote control	
Interruption-free level setting range	setting characteristic: uninterrupted level	0 dB to +20 dB
	setting	
Reverse power from 50 $\Omega$	maximum permissible RF power in output	0.5 W
Maximum permissible DC voltage	at RF power connector	35 V

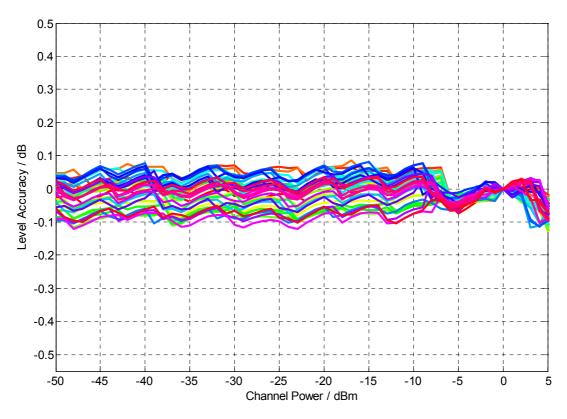


Histogram of level setting times measured via PCIe interface, I/Q modulation from internal baseband, setting characteristic: auto.

<sup>&</sup>lt;sup>1</sup> PEP = peak envelope power.



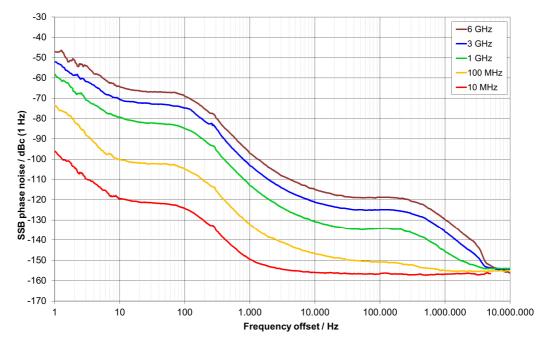
Maximum available level in CW mode, setting characteristic: auto (meas.).



Level linearity for internally generated LTE uplink signal at various test frequencies (meas.).

### **Spectral purity**

Harmonics	level ≤ 8 dBm, CW, I/Q wideband off	< -30 dBc	
Nonharmonics	level > -10 dBm, offset > 10 kHz from ca	level > -10 dBm, offset > 10 kHz from carrier	
	f ≤ 1500 MHz	<-76 dBc	
	1500 MHz < f ≤ 3000 MHz	<-70 dBc	
	3000 MHz < f ≤ 6000 MHz	<-64 dBc	
Subharmonics	level > -10 dBm		
	f ≤ 3000 MHz	<-76 dBc	
	3000 MHz < f ≤ 6000 MHz	<-68 dBc	
Wideband noise	1 MHz $\leq$ f $\leq$ 6 GHz,	< -145 dBc	
	10 MHz carrier offset, level > 5 dBm,		
	setting characteristic: auto,		
	1 Hz measurement bandwidth, CW		
	1 MHz $\leq$ f $\leq$ 6 GHz,	< -135 dBc	
	10 MHz carrier offset, level > 5 dBm,		
	setting characteristic: auto,		
	1 Hz measurement bandwidth, I/Q		
SSB phase noise	20 kHz carrier offset, 1 Hz measurement	t bandwidth	
	f = 1 GHz	< -126 dBc; -133 dBc (meas.)	
	f = 2 GHz	< -120 dBc; -127 dBc (meas.)	
	f = 6 GHz	< -110 dBc; -117 dBc (meas.)	



SSB phase noise with the R&S®SGT-B1 internal OCXO option (meas.).

### Phase coherence (R&S®SGT-K90 option)

The R&S®SGT-K90 option provides phase-coherent RF outputs for two or more instruments. This operating mode supports carrier frequencies greater than 80 MHz (CW, external analog I/Q) or greater than 100 MHz (internal baseband I/Q).

LO coupling modes	This mode corresponds to internal LO operation. The REF/LO OUT connector can provide the internal LO oscillator signal to enable phase-coherent coupling on other instruments.	internal
	This mode corresponds to external LO operation at the REF/LO IN connector. The REF/LO OUT connector can provide the external LO oscillator signal to enable phase-coherent coupling on additional instruments.	external
REF/LO OUT states	The active local oscillator signal can be routed to the REF/LO OUT connector (in order to couple two or more instruments).	REF/LO/OFF
Phase drift over temperature	drift of RF signal phase difference between two LO coupled R&S®SGT100A instruments when changing ambient temperature by +1 °C, f = 6 GHz, level = +10 dBm	0.4° (meas.)

Input of phase coherence signal			
Connector type	REF/LO IN on rear panel	SMA female	
Input impedance		50 Ω (nom.)	
Input level range of external local oscillator		7 dBm to 13 dBm	
signal			
Frequency range of external local	CW and external analog I/Q	80 MHz to 6 GHz	
oscillator signal	internal baseband I/Q	100 MHz to 6 GHz	
Output of phase coherence signal	Output of phase coherence signal		
Connector type	REF/LO OUT on rear panel	SMA female	
Output impedance		50 Ω (nom.)	
Output level range of internal local		7 dBm to 13 dBm	
oscillator signal			
Frequency range of internal local oscillator	CW and external analog I/Q	80 MHz to 6 GHz	
signal	internal baseband I/Q	100 MHz to 6 GHz	

### Simultaneous modulation

	Pulse modulation	I/Q modulation, external analog	I/Q modulation, f > 100 MHz, internal baseband
Pulse modulation		•	•
I/Q modulation, external analog	•		
I/Q modulation, f > 100 MHz, internal	•		
baseband			

• = compatible

### Pulse modulation (R&S®SGT-K22 option)

The R&S®SGT-K22 option provides pulse modulation capabilities. The pulse modulator can be controlled by an internal pulse generator (comes with R&S®SGT-K22) or by an external pulse signal.

Modulation source		external, internal
On/off ratio		> 80 dB
Rise/fall time	10 % to 90 % of RF amplitude	< 20 ns
External pulse modulation delay		45 ns (meas.)
Pulse repetition frequency		0 Hz to 10 MHz
Video feedthrough	level < 10 dBm	< 10 % of RF
Pulse overshoot	f ≥ 500 MHz	< 10 %

### Input for external pulse modulation

Connector type	USER2 on rear panel	SMA female
Input impedance	selectable	10 kΩ or 50 Ω (nom.)
Threshold voltage		1 V (nom.)
Input damage voltage		±5 V
Input polarity	selectable	normal, inverse

### Internal pulse generator

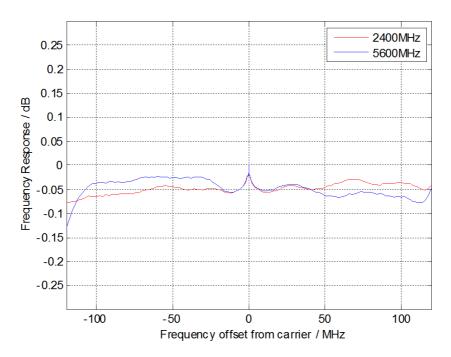
Pulse mode		single pulse, double pulse
Trigger mode	free run, internally triggered	auto
		externally triggered
		externally gated
Active trigger edge		positive or negative
Pulse period		
Setting range		100 ns to 100 s
Setting resolution		10 ns
Pulse width		
Setting range	pulse widths of double pulses can be set	20 ns to 100 s
	independently.	
Setting resolution		10 ns
Pulse delay		
Setting range	with external trigger	0 s to 100 s
Setting resolution	with external trigger	10 ns
Double pulse delay		
Setting range		40 ns to 100 s
Setting resolution		10 ns
External trigger delay jitter		< 20 ns
Pulse/video output	available on USER2 connector on rear	LVTTL signal, 3.3 V (nom.)
	panel in trigger mode: auto	

### I/Q modulation

### I/Q modulator

Operating modes		external analog I/Q, internal baseband I/Q
RF modulation bandwidth		
RF modulation bandwidth	with external analog I/Q inputs, I/Q wideband off	
	80 MHz ≤ f ≤ 1 GHz	±5 % of carrier frequency
	1 GHz < f ≤ 6 GHz	±50 MHz
	with external analog I/Q inputs, I/Q widebar	
	100 MHz < f ≤ 2.5 GHz	±20 % of carrier frequency
	2.5 GHz < f ≤ 6 GHz, I/Q wideband	±500 MHz
	with internal baseband I/Q, I/Q wideband o	n
	1 MHz < f ≤ 100 MHz	frequency range from 1 MHz to 120 MHz
	100 MHz < f ≤ 600 MHz	±20 % of carrier frequency
	f > 600 MHz	±120 MHz
RF frequency response	with external analog I/Q inputs, I/Q widebar	nd off
, , ,	80 MHz < f ≤ 1 GHz,	< 3 dB (meas.)
	up to ±5 % of carrier frequency	, , ,
	f > 1 GHz, up to ±50 MHz	< 3 dB (meas.)
	with external analog I/Q inputs, I/Q widebar	
	100 MHz < f ≤ 2.5 GHz,	< 6 dB (meas.)
	up to ±20 % of carrier frequency	TO GD (MCGO.)
	2.5 GHz < f ≤ 6 GHz, up to ±500 MHz	< 9 dB (meas.)
	with internal baseband I/Q, I/Q wideband	< 1.0 dB; < 0.3 dB (meas.)
	on, optimization mode high quality	< 1.0 db, < 0.3 db (meas.)
Carrier leakage	with external analog I/Q inputs,	< -45 dBc; < -55 dBc (meas.)
Carrier leakage	without input signal, referenced to	< -45 dBC, < -55 dBC (meas.)
	full-scale input <sup>2</sup>	
Cuppression of image sideband for entire	mode: internal baseband I/Q,	> 45 dD: 60 dD (true )
Suppression of image sideband for entire	7	> 45 dB; 60 dB (typ.)
instrument in modulation bandwidth	up to 120 MHz I/Q bandwidth	- 0 F 40 kt l= 0 make l make
Error vector	measured with 16QAM, filter root cosine $\alpha$ level = 0 dBm (PEP)	= 0.5, 10 kHz symbol rate,
	f > 80 MHz, RMS	< (0.4 % + 0.2 % × f/GHz)
	f > 80 MHz, peak value	< (0.8 % + 0.4 % × f/GHz)
3GPP FDD digital standard,	test model 1, 64 DPCHs,	
adjacent channel leakage ratio (ACLR)	level ≤ 10 dBm PEP,	
, , , , , , , , , , , , , , , , , , , ,	frequency range from 1800 MHz to 2200 M	lHz
	5 MHz offset	> 67 dB; 70 dB (meas.)
	10 MHz offset	> 69 dB; 71 dB (meas.)
I/Q impairment settings (analog)		
" a impairment settings (analog)	These impairments are set within the analog I/Q modulator section. They can be used in external wideband I/Q mode and internal baseband I/Q mode for frequencies greater than 100 MHz.	
Offset setting range		-5 % to +5 %
Offset setting resolution		0.01 %
Gain imbalance setting range		-1.0 dB to +1.0 dB
Gain imbalance setting resolution		0.001 dB
Quadrature offset setting range	-8° to +8°	
Quadrature offset setting resolution		0.01°
Quadrature offset setting resolution		0.01

<sup>&</sup>lt;sup>2</sup> Value applies after internal readjustment.



I/Q modulation frequency response with internal baseband (meas.).

### Baseband bypass mode for externally generated I/Q signals

The baseband bypass mode allows generation of modulated signals below the specified frequency range of the I/Q modulator. Externally generated signals applied to the I or Q baseband input connector can be leveled and amplified by the instrument and are provided at the RF output connector.

For the baseband bypass mode, only the data specified in this section is valid.

Level setting range		-120 dBm to +25 dBm
Specified level range		-120 dBm to +15 dBm
Frequency response	1 MHz $\leq$ f $\leq$ 80 MHz, level = 10 dBm	< 3 dB; < 1 dB (meas.)
Level error	attenuator mode: auto, temperature range from +18 °C to +33 °C, referenced to full-scale input at I or Q connector, 1 MHz ≤ f ≤ 80 MHz	< 3 dB
Level linearity	attenuator mode: fixed,	< 2 dB; < 0.5 dB (meas.)
	for setting range of 0 dB to +20 dB	

### Analog I/Q inputs

Connector types	I, Q on rear panel	SMA female
Input impedance		50 Ω (nom.)
VSWR	up to 100 MHz	< 1.2
	100 MHz up to 500 MHz	< 1.5
Input voltage for full-scale input		$\sqrt{{\rm V_i}^2 + {\rm V_q}^2} = 0.5 {\rm V}$ (nom.)
Input damage voltage		±1 V

### Internal baseband I/Q

D/A converter	resolution	16 bit	
Aliasing filter	with amplitude, group-delay and Si co	with amplitude, group-delay and Si correction	
	bandwidth (drop to -0.1 dB)	120 MHz (nom.)	
	D/A converter interpolation spectra	a e e e e e e e e e e e e e e e e e e e	
	up to 120 MHz	< -80 dBc	
I/Q impairments	I offset, Q offset		
	setting range	-10 % to +10 %	
	resolution	0.01 %	
	gain imbalance		
	setting range	-1 dB to +1 dB	
	resolution	0.001 dB	
	quadrature offset		
	setting range	-10° to +10°	
	resolution	0.01°	

# Analog I/Q outputs (R&S®SGT-K16 option)

Output impedance		
Single-ended		50 Ω
Differential		100 Ω
Output voltage	output voltage depends on set modulati	ion signal
Single-ended	EMF	0.02 V to 2 V (V <sub>p</sub> )
Resolution		1 mV
Differential	EMF	0.04 V to 4 V (V <sub>pp</sub> )
Resolution		2 mV
Bias voltage (single-ended and differential)	EMF	-3.6 V to +3.6 V <sup>3</sup>
Resolution		0.1 mV
Uncertainty		1 % + 4 mV
Offset voltage		
Differential	EMF	-300 mV to +300 mV
Resolution		0.1 mV
Uncertainty		1 % + 0.1 % × bias voltage + 1 mV
Single-ended	EMF	< 1 mV
Frequency response <sup>4</sup>	at $R_L = 50 \Omega$	
Magnitude	up to 10 MHz	< 0.15 dB; 0.03 dB (meas.)
	up to 120 MHz	< 0.3 dB; 0.05 dB (meas.)
I/Q balance	up to 10 MHz	< 0.05 dB; 0.02 dB (meas.)
	up to 120 MHz	< 0.15 dB; 0.05 dB (meas.)
Spectral purity <sup>4</sup>	at $R_L = 50 \Omega$	
SFDR (sine)	up to 2 MHz	> 70 dB
	up to 20 MHz	60 dB (meas.)
Wideband noise 4	10 MHz sine wave at 1 MHz offset	-150 dBc (typ.)

 $<sup>^{3}\,\,</sup>$  The magnitude of the sum of the output voltage (EMF) and the bias voltage (EMF) must not exceed:

 $<sup>\</sup>bullet~$  4 V for termination with 100  $\Omega$  from I to IN and Q to QN

<sup>• 3</sup> V for termination with 50  $\Omega$  to ground

<sup>&</sup>lt;sup>4</sup> Mode: fixed (output voltage =  $1.0 \text{ V}_p$  (EMF), bias voltage = 0.0 V, offset voltage = 0.0 V).

### **Envelope tracking (R&S®SGT-K540 option)**

General		
Envelope voltage adaptation	auto normalized, au	to power, manual
Output type	single-ended, differ	ential
Bias voltage	see "Differential analog I/Q outputs"	
Offset voltage	see "Differential analog I/Q outputs"	
Envelope to RF delay	1	
Setting range	–1 μs to +1 μs	
Setting resolution	1 ps	
Shaping	off, linear, from tabl	e, polynomial,
	detroughing	
Envelope voltage adaptation modes: au	to normalized and auto power	
Power amplifier input power P <sub>in</sub>		
Setting range	-145.00 dB to +30.	00 dB
Setting resolution	0.01 dB	
Power amplifier supply voltage V <sub>cc</sub>	V <sub>cc</sub> = envelope voltage × DC modulator gain + V <sub>CC, Offset</sub>	
DC modulator gain	-20.00 dB to +20.0	O dB
Power amplifier offset voltage V <sub>cc</sub> offset	0 V to 30 V	
Envelope voltage adaptation mode: ma	nual	
Pregain		
Setting range	-20.00 dB to 0.00 d	В
Setting resolution	0.01 dB	

### Envelope ARB (R&S®SGT-K543 option)

The R&S®SGT-K510 option must be installed.

The R&S®SGT-K543 option allows configuring of two independent baseband signals in the arbitrary waveform generator for envelope tracking tests.

With the R&S®SGT-K543, the signals generated in baseband A are fixed mapped to the RF output. Signals generated in baseband B (ARB envelope) are mapped to the Analog I and I\_Bar outputs (Analog Q is disabled).

Independent clock rates in both basebands can be adjusted and the ARB memory is shared.

# AM/AM, AM/φM predistortion (R&S®SGT-K541 option)

State	on, off
Maximum input power (PEP <sub>in</sub> max.)	
Setting range	-145.00 dB to +30.00 dB
Setting resolution	0.01 dB
Shaping	polynomial, from table

### Arbitrary waveform generator (R&S®SGT-K510 option)

Waveform length	. ,	1 sample to 32 Msample
		in one-sample steps
	with R&S®SGT-K511 option	1 sample to 256 Msample
		in one-sample steps
	with R&S®SGT-K511	1 sample to 1 Gsample
	and R&S®SGT-K512 options	in one-sample steps
Nonvolatile memory		SSD 120 Gbyte
Sample rate		400 Hz to 75 MHz
	with R&S®SGT-K521 option	400 Hz to 150 MHz
	with R&S®SGT-K521	400 Hz to 200 MHz
	and R&S®SGT-K522 options	10011210 200111112
	with R&S®SGT-K521	400 Hz to 300 MHz
	and R&S®SGT-K522	
	and R&S®SGT-K523 options	
Sample resolution	equivalent to D/A converter	16 bit
Sample clock source	equivalent to En Converter	internal, external
Sample frequency error	internal clock	< (5 × 10 <sup>-14</sup> + reference frequency error)
sumple frequency error	internal clock	× sample rate (nom.)
Bandwidth (RF) using the maximum		60 MHz (nom.)
sample rate	with R&S®SGT-K521 option	120 MHz (nom.)
sample rate	with R&S®SGT-K521	160 MHz (nom.)
	and R&S®SGT-K522 options	100 MHz (HoH)
	with R&S®SGT-K521	240 MHz (nom.)
	and R&S®SGT-K522	240 MHZ (HOHL)
	and R&S®SGT-K523 options	
Bandwidth (RF) using a reduced sample		ed to the internal sample rate of 300 MHz.
rate (drop to –0.1 dB)	The wavelorm is automatically interpolate	0.8 × sample rate (nom.)
	aatting range	0.6 × Sample rate (nom.)
Frequency offset	setting range	20 MHz to 20 MHz
	with DaoRoot Krod andian	-30 MHz to 30 MHz
	with R&S®SGT-K521 option with R&S®SGT-K521	-60 MHz to 60 MHz
		-80 MHz to 80 MHz
	and R&S®SGT-K522 options	400 MH = 4- 400 MH =
	with R&S®SGT-K521	–120 MHz to 120 MHz
	and R&S®SGT-K522	
	and R&S®SGT-K523 options	0.04    -
	resolution	0.01 Hz
	frequency accuracy	< (5 × 10 <sup>-10</sup> + reference frequency error)
<del>-</del> · ·		× frequency offset (nom.)
Triggering	source	internal, external
	operating modes	auto, retrig, armed auto, armed retrig,
		single, next
	external trigger delay (in sample)	2
	setting range	0 to (2 <sup>16</sup> – 1)
	resolution	0.01
	jitter	±1.67 ns (nom.)
	external trigger inhibit (in sample)	
	setting range	0 to (2 <sup>26</sup> – 1)
	resolution	1
	external trigger pulse width	> 20 ns (nom.)
Marker outputs	number	2
	level	LVTTL
	operating modes	unchanged, restart, pulse, pattern, ratio,
		trigger
	marker delay (in sample)	
	setting range	0 to (waveform length – 1)
	setting range without recalculation	0 to 2000
	resolution of setting	1

### Multisegment and multicarrier arbitrary waveform mode

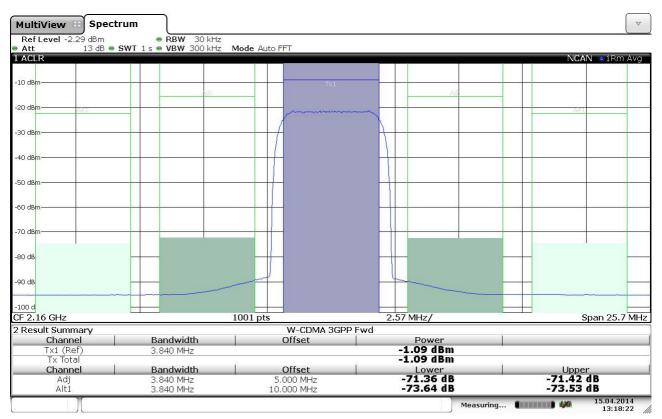
Multisegment waveform	number of segments	100 segments (max.)
Waveloili	changeover modes	GUI, remote control, external trigger
	extended trigger modes	same segment, next segment,
	exterided trigger modes	next segment seamless, sequencer
	changeover time at 50 MHz clock rate	5 μs (meas.)
		5 µs (meas.)
	(external trigger, without clock change)	output up to and of ourrent comment
	seamless changeover	output up to end of current segment,
		followed by changeover to next segment
	sequencer play list length	1024 (max.)
	sequencer segment repetitions	65535 (max.)
Multicarrier waveform	number of carriers	32 (max.)
	carrier spacing	
	setting range	depends on number of carriers and
		bandwidth (RF)
	resolution	0.01 Hz
	crest factor modes	maximize, minimize, off
	signal period modes	longest file, shortest file, user (max. 1 s)
	single carrier gain	
	setting range	-80 dB to 0 dB
	resolution	0.01 dB
	single carrier start phase	
	setting range	0° to 360°
	resolution	0.01°
	single carrier delay	
	setting range	0 s to 1 s
	resolution	1 ns

### Operation with R&S®WinIQSIM2™:

The software supports download of I/Q data and basic control of the arbitrary waveform generator.

### Modulation performance for GSM/EDGE and 3GPP FDD digital standards

GSM/EDGE	with R&S®SGT-K240 option	
	level ≤ 13 dBm PEP, frequency range from 400 MHz to 2000 MHz	
Burst on/off ratio	100 dB (meas.)	
Phase error	MSK, Gaussian filter B × T = 0.3	
	RMS	< 0.4°; 0.15° (typ.)
	peak	0.4° (meas.)
Error vector magnitude	8PSK EDGE, Gaussian linearized filter,	< 0.5 %; 0.25 % (typ.)
	RMS	
Power density spectrum	values measured with 30 kHz resolution bandwidth, referenced to level in band center	
	without power ramping	
	200 kHz offset	< -34 dB; -38 dB (typ.)
	400 kHz offset	< -66 dB; -70 dB (typ.)
	600 kHz offset	< -74 dB; -78 dB (typ.)
3GPP FDD	with R&S®SGT-K242 option	
	level ≤ 0 dBm RMS, frequency range from 1800 MHz to 2200 MHz	
Error vector magnitude	1 DPCH, RMS	< 0.8 %; 0.4 % (typ.)
Adjacent channel leakage ratio (ACLR)	test model 1, 64 DPCHs	
	offset 5 MHz	> 68 dB; 71 dB (typ.)
	offset 10 MHz	> 70 dB; 73 dB (typ.)



Date: 15.APR.2014 13:18:22

Digital standard 3GPP FDD test model 1, 64 DPCHs ACLR (meas.).

### Digital standards with R&S®WinIQSIM2™

R&S®WinIQSIM2™ requires an external PC.

The options are described in the R&S®WinIQSIM2™ data sheet (PD 5213.7460.22).

#### Cellular standards

EUTRA/LTE (R&S®SGT-K255 option)

EUTRA/LTE Rel. 9 and enhanced features (R&S®SGT-K284 option; R&S®SGT-K255 option required)

EUTRA/LTE Rel. 10/LTE-Advanced (R&S®SGT-K285 option; R&S®SGT-K255 option required)

3GPP FDD (R&S®SGT-K242 option)

3GPP FDD/HSPA/HSPA+, enhanced BS/MS tests (R&S®SGT-K283 option; R&S®SGT-K242 option required)

GSM/EDGE (R&S®SGT-K240 option)

EDGE EVOLUTION (R&S®SGT-K241 option; R&S®SGT-K240 option required)

CDMA2000® (R&S®SGT-K246 option)

1xEV-DO (R&S®SGT-K247 option)

1xEV-DO Rev. B (R&S®SGT-K287 option; R&S®SGT-K247 option required)

TD-SCDMA (3GPP TDD LCR) (R&S®SGT-K250 option)

TD-SCDMA (3GPP TDD LCR) enhanced BS/MS test including HSDPA (R&S®SGT-K251 option; R&S®SGT-K250 option required)

TETRA Release 2 (R&S®SGT-K268 option)

#### Wireless connectivity standards

IEEE 802.11 a/b/g/n (R&S®SGT-K254 option)

IEEE 802.11 ac (R&S®SGT-K286 option; R&S®SGT-K254 option required)

IEEE 802.16 (R&S®SGT-K249 option)

Bluetooth® EDR/low energy (R&S®SGT-K260 option)

NFC A/B/C (R&S®SGT-K289 option)

#### **Navigation standards**

GPS 1 satellite (R&S®SGT-K244 option)

Galileo 1 satellite (R&S®SGT-K266 option)

Glonass 1 satellite (R&S®SGT-K294 option)

BeiDou 1 satellite (R&S®SGT-K407 option)

#### **Broadcast standards**

DVB-H/DVB-T (R&S®SGT-K252 option)

DAB/T-DMB (R&S®SGT-K253 option)

#### Other standards and modulation systems

Multicarrier CW signal generation (R&S®SGT-K261 option)

Additive white Gaussian noise (AWGN) (R&S®SGT-K262 option)

### Digital baseband connectivity (R&S®SGT-K18 option)

External digital I/Q signals can be fed in to the baseband section. The digital I/Q connectivity can be used for lossless connection of the R&S®SGT100A to the digital I/Q output of other Rohde & Schwarz instruments (e.g. the R&S®SMW200A vector signal generator). One R&S®SGT-K18 option can be installed.

### Input parameters

Input level	peak level		
	setting range	-60 dB to +3 dB referenced to full scale	
	resolution	0.01 dB	
	crest factor		
	setting range	0 dB to +30 dB	
	resolution	0.01 dB	
	The adjust level function automatically de	etermines the peak level and crest factor of the	
	input signal.		
Frequency offset		enter frequency of the input signal can be	
	shifted in the baseband. The restrictions	caused by the modulation bandwidth apply.	
	setting range	-30 MHz to 30 MHz	
	with R&S®SGT-K521 option	-60 MHz to 60 MHz	
	with R&S®SGT-K521	-80 MHz to 80 MHz	
	and R&S®SGT-K522 options		
	with R&S®SGT-K521	-120 MHz to 120 MHz	
	and R&S®SGT-K522		
	and R&S®SGT-K523 options		
	resolution	0.01 Hz	
	frequency accuracy	< (5 × 10 <sup>-10</sup> + reference frequency error)	
		× frequency offset (nom.)	
I/Q swap	I and Q signals swapped	on/off	
Interface	standard	in line with Rohde & Schwarz standard for	
		digital I/Q interface	
	level	LVDS	
	connector	26-pin MDR	
	data rate	up to 200 MHz	
I/Q sample rate	With source 'user-defined', the sample ra	te must be entered via the parameter 'sample	
·		rate', no I/Q data clock being necessary. With source 'digital I/Q in', the sample rate will	
		be estimated on the basis of the applied I/Q data clock.	
	source	user-defined, digital I/Q in	
	sample rate	400 Hz to 200 MHz, max. sample rate	
		depending on interface data rate	
	resolution (user-defined)	0.001 Hz	
	frequency uncertainty (user-defined)	< 5 × 10 <sup>-14</sup>	
I/Q data	resolution	18 bit	
	logic format	two's complement	
	bandwidth	0.33 × sample rate	
Control signals	markers	4	
2	data valid	valid samples marked in data stream	

### Internal additive white Gaussian noise (AWGN, R&S®SGT-K62 option)

Addition of an AWGN signal of settable bandwidth and settable C/N ratio or  $E_\text{b}/N_0$  to a wanted signal.

Noise	distribution density	Gaussian, statistical, separate for I and Q
	crest factor	> 15 dB
	periodicity	> (2 <sup>800</sup> – 1 )/300 MHz
C/N, E <sub>b</sub> /N <sub>0</sub>	setting range	-30 dB to +30 dB
	resolution	0.1 dB
	uncertainty for system bandwidth = symbol rate	< 0.1 dB
	-24 dB < C/N < 30 dB and	
	crest factor < 12 dB	
System bandwidth	bandwidth for determining noise power	•
	setting range	
		1 kHz to 60 MHz
	with R&S®SGT-K521 option	1 kHz to 120 MHz
	with R&S®SGT-K521	1 kHz to 160 MHz
	and R&S®SGT-K522 options	
	with R&S®SGT-K521	1 kHz to 240 MHz
	and R&S®SGT-K522	
	and R&S®SGT-K523 options	
	setting resolution	100 Hz

### **Remote control**

Systems		PCI Express (single lane)
		Ethernet (TCP/IP) 10/100/1000BASE-T
		USB 2.0
Command set	remote control via Ethernet, USB	SCPI 1999.5 or compatible command sets
	remote control via PCI Express	Rohde & Schwarz instrument driver

### **Connectors**

### Rear panel connectors

RF 50 Ω	RF output	SMA female
REF/LO IN	reference frequency input or	SMA female
	external LO signal input	
REF/LO OUT	reference frequency output or	SMA female
	internal LO signal output	
I, Q	input connector for I and Q baseband	SMA female
	signals,	
	input for I/Q vector-modulated IF signals	
	up to 80 MHz	
I, IN, Q, QN	output connector for differential I and Q	SMB male
	baseband signals,	
	output for envelope tracking signals	
DIG IQ IN	digital input connectivity in line with	26-pin MDR
	R&S®Digital I/Q Interface	
USER1	multipurpose input/output	SMB male
USER2	pulse and multipurpose input/output	SMA female
USB IN	remote control of instrument	USB (micro USB)
LAN	remote control of instrument	RJ-45
PCI Express	remote control of instrument	single lane, in line with PCI Express
		external cabling specification

### **General data**

Power supply			
AC input voltage range		100 V to 240 V ± 10 %	
AC supply frequency		50 Hz to 60 Hz, -5 %/+5 %	
Max. input current		1.7 A	
Power consumption		65 W (meas.)	
Power factor correction		in line with EN 61000-3-2	
Electrical safety		1	
Compliance		in line with IEC 61010-1, EN 61010-1, CAN/CSA-C22.2 No. 61010-1-04, UL 61010-1	
Test mark		VDE-GS, cCSA <sub>US</sub>	
EMC			
Electromagnetic compatibility		in line with EN 55011 class A, EN 61326-1 (industrial environment), EN 61326-2-1	
Mechanical resistance			
Vibration	sinusoidal	5 Hz to 150 Hz, max. 2 g at 55 Hz, const. 0.5 g at 55 Hz to 150 Hz, in line with EN 60068-2-6	
	random	10 Hz to 300 Hz, acceleration 1.2 g (RMS), in line with EN 60068-2-64	
Shock		in line with MIL-STD-810E, method no. 516.4, procedure I, 40 g shock spectrum	
Environmental conditions			
Temperature range	operating temperature range	0 °C to +50 °C, in line with EN 60068-2-1, EN 60068-2-2	
01: 1: 1:	storage temperature range	-40 °C to +71 °C	
Climatic resistance		+40 °C/95 % rel. humidity, in line with EN 60068-2-30	
Altitude	operating	up to 4600 m	
	storage	up to 4600 m	
Dimensions	W×H×D	250 mm × 52.5 mm × 401 mm (9.84 in × 2.07 in × 15.79 in) 1 HU, ½ 19" rack width	
Weight	when fully equipped	4.0 kg (8.82 lb)	
Calibration interval	· A - A- LL		
Recommended calibration interval	40 h/week operation in the full range of the specified environmental conditions	3 years	

# **Ordering information**

Designation	Туре	Order No.
SGMA Vector RF Source, 1 MHz to 3 GHz RF, baseband hardware included	R&S®SGT100A	1419.4501.02
Including power cable, quick start guide and CD-ROM (with operating and serv	rice manual)	
RF options		
Frequency Extension to 6 GHz	R&S®SGT-KB106	1419.5708.02
Reference Oscillator OCXO	R&S®SGT-B1	1419.5608.02
Pulse Modulation	R&S®SGT-K22	1419.6279.02
Phase Coherent Input/Output	R&S®SGT-K90	1419.6333.02
Baseband options		
Digital Baseband Connectivity	R&S®SGT-K18	1419.6240.02
Differential Analog I/Q Outputs	R&S®SGT-K16	1419.8007.02
ARB Baseband Generator, 32 Msample, 60 MHz RF bandwidth	R&S®SGT-K510	1419.7500.02
ARB Memory Extension to 256 Msample	R&S®SGT-K511	1419.6362.02
ARB Memory Extension to 1 Gsample	R&S®SGT-K512	1419.6391.02
ARB Bandwidth Extension to 120 MHz RF bandwidth	R&S®SGT-K521	1419.6427.02
ARB Bandwidth Extension to 160 MHz RF bandwidth	R&S®SGT-K522	1419.6456.02
ARB Bandwidth Extension to 240 MHz RF bandwidth	R&S®SGT-K523	1419.7952.02
Envelope Tracking	R&S®SGT-K540	1419.7800.02
AM/AM AM/PM Predistortion	R&S®SGT-K541	1419.7852.02
Envelope ARB	R&S®SGT-K543	1419.7900.02
Noise generation		
Additive White Gaussian Noise (AWGN)	R&S®SGT-K62	1419.6304.02
Digital modulation systems using R&S®WinIQSIM2™ 5	·	
GSM/EDGE	R&S®SGT-K240	1419.5950.02
EDGE Evolution	R&S®SGT-K241	1419.6004.02
3GPP FDD	R&S®SGT-K242	1419.6056.02
GPS	R&S®SGT-K244	1419.6104.02
CDMA2000® incl. 1xEV-DV	R&S®SGT-K246	1419.6156.02
1xEV-DO Rev. A	R&S®SGT-K247	1419.6204.02
IEEE 802.16	R&S®SGT-K249	1419.6504.02
TD-SCDMA	R&S®SGT-K250	1419.6556.02
TD-SCDMA Enhanced BS/MS Tests	R&S®SGT-K251	1419.6604.02
DVB-H	R&S®SGT-K252	1419.6656.02
DAB/T-DMB	R&S®SGT-K253	1419.6704.02
IEEE 802.11a/b/g/n	R&S®SGT-K254	1419.6756.02
EUTRA/LTE	R&S®SGT-K255	1419.6804.02
Bluetooth® EDR	R&S®SGT-K260	1419.6856.02
Multicarrier CW Signal Generation	R&S®SGT-K261	1419.6904.02
Additive White Gaussian Noise (AWGN)	R&S®SGT-K262	1419.6956.02
Galileo	R&S®SGT-K266	1419.7000.02
TETRA Release 2	R&S®SGT-K268	1419.7052.02
3GPP FDD HSPA/HSPA+	R&S®SGT-K283	1419.7100.02
EUTRA/LTE Release 9, enhanced features	R&S®SGT-K284	1419.7152.02
EUTRA/LTE Release 10 (LTE Adanced)	R&S®SGT-K285	1419.7200.02
IEEE 802.11ac	R&S®SGT-K286	1419.7252.02
1xEV-DO Rev. B	R&S®SGT-K287	1419.7300.02
NFC A/B/F	R&S®SGT-K289	1419.7352.02
Glonass	R&S®SGT-K294	1419.7400.02
BeiDou	R&S®SGT-K407	1419.7452.02
LTE Release 11 + enhanced features	R&S®SGT-K412	1419.7600.02
Waveform package for signals from R&S®WinIQSIM2™ 5	<u> </u>	
1 Waveform	R&S®SGT-K200	1419.5850.71
5 Waveforms	R&S®SGT-K200	1419.5850.72
50 Waveforms	R&S®SGT-K200	1419.5850.75
Digital standards using an external PC software or waveforms		
Pulse Sequencing	R&S®SGT-K300	1419.7652.02
	R&S®SGT-K301	1419.7700.02

<sup>&</sup>lt;sup>5</sup> R&S<sup>®</sup>WinIQSIM2<sup>™</sup> requires an external PC.

Recommended extras				
Documentation of Calibration Values	R&S®DCV-2	0240.2193.18		
Hardcopy manuals (in English)		1176.8674.02		
19" Rack Adapter, suitable for installation of two R&S®SGMA instruments	R&S®ZZA-KN20	1175.3191.00		
(for two 1 HU instruments next to each other)				
19" Rack Adapter (for one instrument and spacing module)	R&S®ZZA-KN21	1175.3204.00		
SGMA Adapter	R&S®SGS-Z8	1416.2914.02		
SGT Adapter Cable Set	R&S®SGT-Z9	1419.8059.02		
Cable for connecting digital baseband interfaces	R&S®SMU-Z6	1415.0201.02		

Service options		
Extended Warranty, one year	R&S®WE1	Please contact your
Extended Warranty, two years	R&S®WE2	local Rohde & Schwarz
Extended Warranty, three years	R&S®WE3	sales office.
Extended Warranty, four years	R&S®WE4	
Extended Warranty with Calibration Coverage, one year	R&S®CW1	
Extended Warranty with Calibration Coverage, two years	R&S®CW2	
Extended Warranty with Calibration Coverage, three years	R&S®CW3	
Extended Warranty with Calibration Coverage, four years	R&S®CW4	

#### Extended warranty with a term of one to four years (WE1 to WE4)

Repairs carried out during the contract term are free of charge <sup>6</sup>. Necessary calibration and adjustments carried out during repairs are also covered. Simply contact the forwarding agent we name; your product will be picked up free of charge and returned to you in top condition a couple of days later.

#### Extended warranty with calibration (CW1 to CW4)

Enhance your extended warranty by adding calibration coverage at a package price. This package ensures that your Rohde & Schwarz product is regularly calibrated, inspected and maintained during the term of the contract. It includes all repairs <sup>6</sup> and calibration at the recommended intervals as well as any calibration carried out during repairs or option upgrades.

The Bluetooth® word mark and logos are registered trademarks owned by Bluetooth SIG, Inc. and any use of such marks by Rohde & Schwarz is under license.

CDMA2000® is a registered trademark of the Telecommunications Industry Association (TIA-USA).

For product brochure, see PD 3607.0217.12 and www.rohde-schwarz.com

<sup>&</sup>lt;sup>6</sup> Excluding defects caused by incorrect operation or handling and force majeure. Wear-and-tear parts are not included.

#### Service that adds value

- Worldwide
- Local and personalized
- Customized and flexible
- Uncompromising qualit
- Long-term dependability

#### About Rohde & Schwarz

The Rohde & Schwarz electronics group offers innovative solutions in the following business fields: test and measurement, broadcast and media, secure communications, cybersecurity, radiomonitoring and radiolocation. Founded more than 80 years ago, this independent company has an extensive sales and service network and is present in more than 70 countries. The electronics group is among the world market leaders in its established business fields. The company is headquartered in Munich, Germany. It also has regional headquarters in Singapore and Columbia, Maryland, USA, to manage its operations in these regions.

#### Sustainable product design

- Environmental compatibility and eco-footprint
- Energy efficiency and low emissions
- Longevity and optimized total cost of ownership

 $\begin{array}{c} \text{Certified Quality Management} \\ ISO\,9001 \end{array}$ 

Certified Environmental Management

#### Rohde & Schwarz GmbH & Co. KG

www.rohde-schwarz.com

### **Regional contact**

- Europe, Africa, Middle East | +49 89 4129 12345 customersupport@rohde-schwarz.com
- North America | 1 888 TEST RSA (1 888 837 87 72) customer.support@rsa.rohde-schwarz.com
- Latin America | +1 410 910 79 88 customersupport.la@rohde-schwarz.com
- Asia Pacific | +65 65 13 04 88 customersupport.asia@rohde-schwarz.com
- I China | +86 800 810 82 28 | +86 400 650 58 96 customersupport.china@rohde-schwarz.com

